

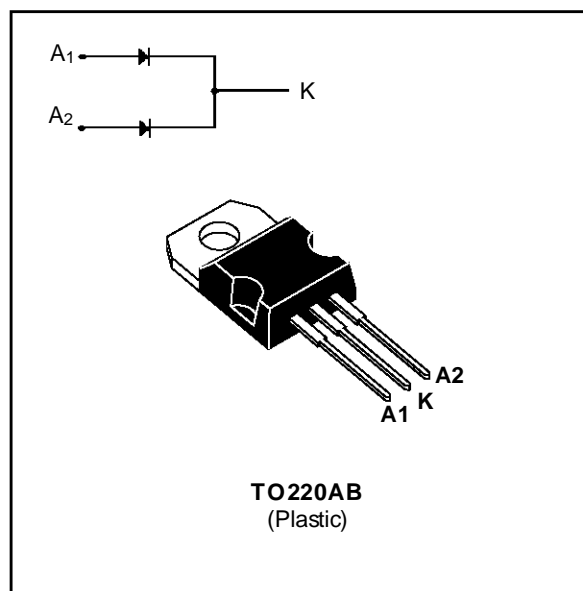
POWER SCHOTTKY RECTIFIER

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- EXTREMELY FAST SWITCHING
- LOW FORWARD VOLTAGE DROP
- HIGH AVALANCHE CAPABILITY
- LOW THERMAL RESISTANCE
- INSULATED PACKAGE :
Insulating voltage = 2000V DC
Capacitance = 12pF

DESCRIPTION

Dual center tap schottky rectifier suited for switch-mode power supply and high frequency DC to DC converters.

Packaged in TO220AB, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
I _{F(RMS)}	RMS Forward Current		Per diode 30	A
I _{F(AV)}	Average Forward Current	T _c = 135°C δ = 0.5	Per diode 15 Per device 30	A
I _{FSM}	Surge Non Repetitive Forward Current	T _p = 10 ms Sinusoidal	Per diode 220	A
I _{RRM}	Peak Repetitive Reverse Current	T _p = 2 μs F = 1KHz	Per diode 1	A
T _{stg} T _j	Storage and Junction Temperature Range		- 65 to + 150 - 65 to + 150	°C
dV/dt	Critical Rate of Rise of Reverse Voltage		1000	V/μs

Symbol	Parameter	STPS		Unit
		3035CT	3045CT	
V _{RRM}	Repetitive Peak Reverse Voltage	35	45	V

THERMAL RESISTANCE

Symbol	Parameter		Value	Unit
R _{TH(j-c)}	Junction-case	Per diode total	1.60 0.85	°C/W
R _{TH(c)}	Coupling		0.10	°C/W

When the diodes 1 and 2 are used simultaneously :
 $\Delta T_{J(\text{diode } 1)} = P(\text{diode } 1) \times R_{TH(\text{Per diode})} + P(\text{diode } 2) \times R_{TH(c)}$

STPS3035CT/STPS3045CT

ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS PER DIODE

Symbol	Tests Conditions		Min.	Typ.	Max.	Unit
I_R^{**}	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			200	μA
	$T_j = 125^\circ\text{C}$				40	mA
V_F^*	$T_j = 125^\circ\text{C}$	$I_F = 30\text{ A}$			0.72	V
	$T_j = 125^\circ\text{C}$	$I_F = 15\text{ A}$			0.57	
	$T_j = 25^\circ\text{C}$	$I_F = 30\text{ A}$			0.84	

Pulse test : * $t_p = 380\ \mu\text{s}$, duty cycle < 2 %
 ** $t_p = 5\ \text{ms}$, duty cycle < 2%

To evaluate the conduction losses use the following equation :
 $P = 0.42 \times I_{F(AV)} + 0.01 I_{F(RMS)}^2$

Fig. 1 : Average forward power dissipation versus average forward current. (Per diode)

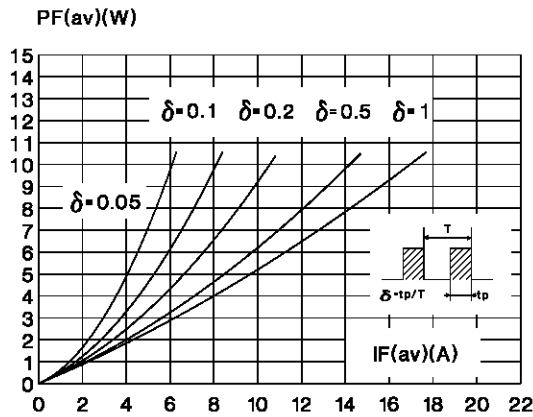


Fig. 3 : Non repetitive surge peak forward current versus overload duration. (Maximum values) (Per diode)

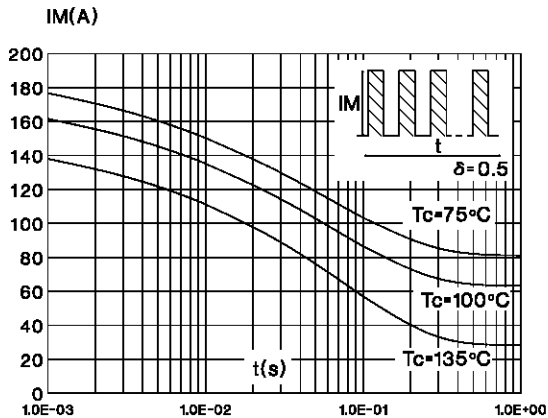


Fig. 2 : Average current versus ambient temperature. (duty cycle : 0.5) (Per diode)

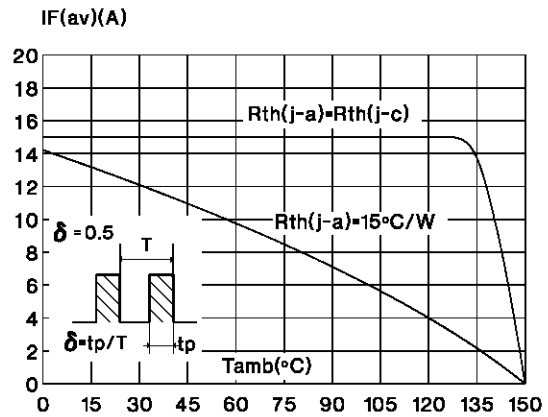


Fig. 4 : Relative variation of thermal transient impedance junction to case versus pulse duration.

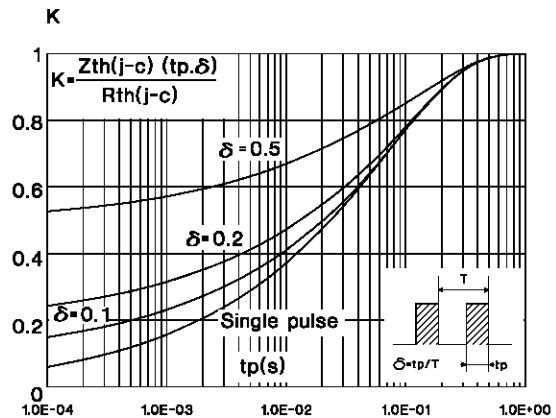


Fig. 5 : Reverse leakage current versus reverse voltage applied. (Typical values) (Per diode)

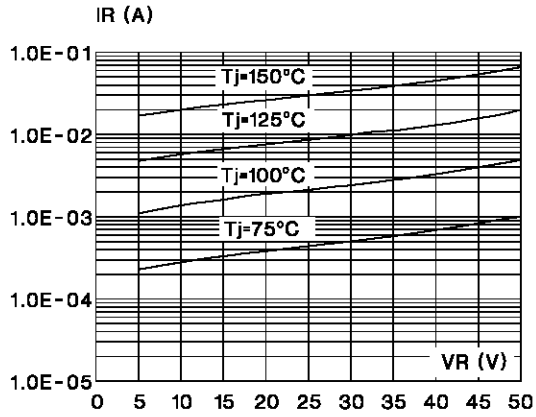


Fig. 6 : Junction capacitance versus reverse voltage applied. (Typical values) (Per diode)

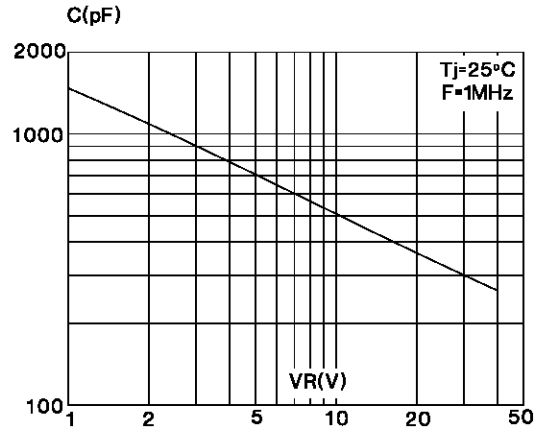
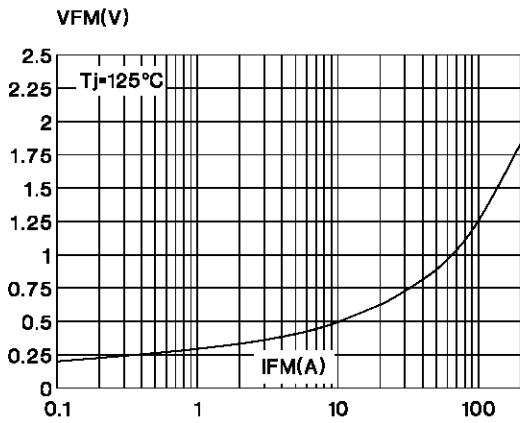
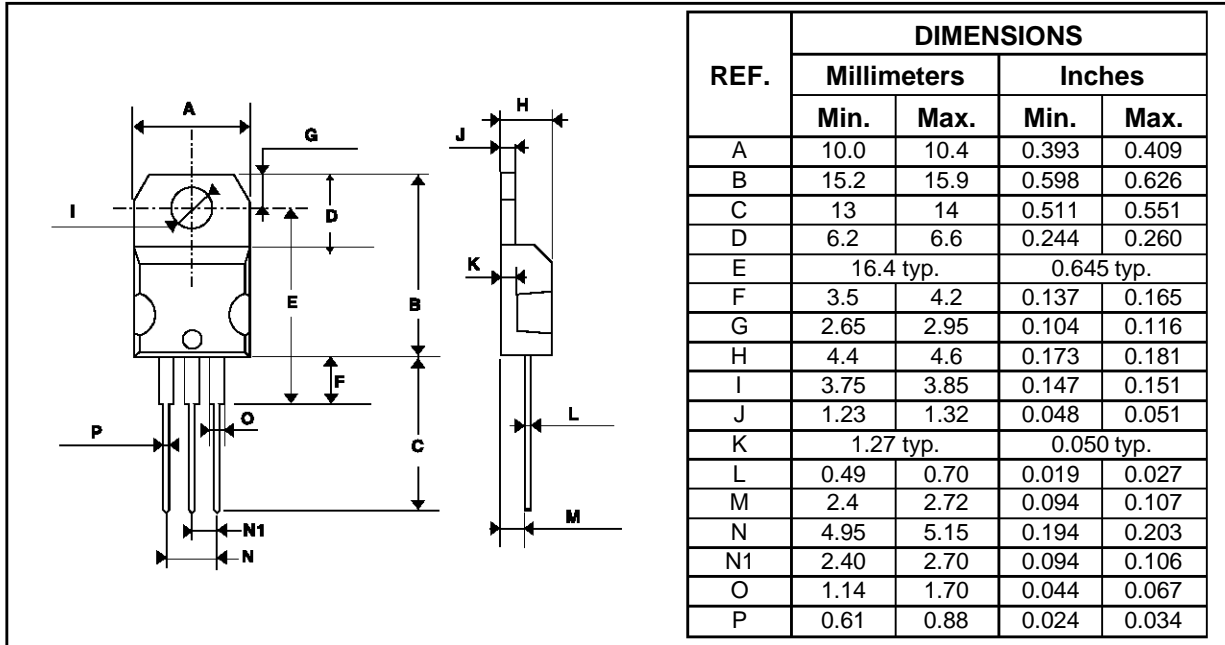


Fig. 7 : Forward voltage drop versus forward current. (Maximum values) (Per diode)



STPS3035CT/STPS3045CT

PACKAGE MECHANICAL DATA TO220AB (JEDEC outline)



Cooling method : C
 Marking : Type number
 Weight : 2 g
 Recommended torque value : 0.55m.N
 Maximum torque value : 0.7m.N

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